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# Output

Outputs of this project are based on the following paper:

**Prasongkit, J\***; Amorim, R. G.; Chakraborty, S.; Ahuja, R; Scheicher, R. H.; Amornkitbamrung, V. Highly Sensitive and Selective Gas Detection Based on Sillicene. *J. Phys. Chem. C.*, DOI: 10.1021/acs.jpcc.5b03635

Note that \* indicates the corresponding author.